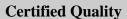


RN1309(TE85L,F)

Request a Quote

RN1309(TE85L,F) Information

www.melsener.com	Part Number	RN1309(TE85L,F)
	Manufacturer	Toshiba Semiconductor and Storage
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single, Pre-Biased
	Description	TRANS PREBIAS NPN 0.1W USM
	Package	SC-70, SOT-323
-		For the pricing/inventory/lead time, please contact
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RN1309(TE85L,F) Specifications

	Report errors?
Supplier Device Package	USM
Package / Case	SC-70, SOT-323
Mounting Type	Surface Mount
Power - Max	100mW
Frequency - Transition	250MHz
Current - Collector Cutoff (Max)	500nA
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA
DC Current Gain (hFE) (Min) @ Ic, Vce	70 @ 10mA, 5V
Resistor - Emitter Base (R2) (Ohms)	22k
Resistor - Base (R1) (Ohms)	47k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	NPN - Pre-Biased
Series	-
Package	SC-70, SOT-323
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	Toshiba Semiconductor and Storage
Manufacturer Part Number	RN1309(TE85L,F)

RN1309(TE85L,F) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1309(TE85L,F) Payment Methods



RN1309(TE85L,F) Shipping Methods



If you have any question about RN1309(TE85L,F), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com